

RJK0316DSP

Silicon N Channel Power MOS FET Power Switching

REJ03G1598-0300

Rev.3.00

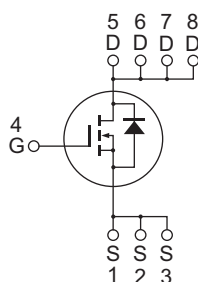
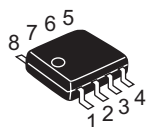
Oct 16, 2007

Features

- High speed switching
- Capable of 4.5 V gate drive
- Low drive current
- High density mounting
- Low on-resistance
 $R_{DS(on)} = 5.3 \text{ m}\Omega$ typ. (at $V_{GS} = 10 \text{ V}$)

Outline

RENESAS Package code: PRSP0008DD-D
(Package name: SOP-8<FP-8DAV>)



1, 2, 3 Source
4 Gate
5, 6, 7, 8 Drain

Absolute Maximum Ratings

($T_a = 25^\circ\text{C}$)

Item	Symbol	Ratings	Unit
Drain to source voltage	V_{DSS}	30	V
Gate to source voltage	V_{GSS}	+16/-12	V
Drain current	I_D	16	A
Drain peak current	$I_{D(pulse)}$ ^{Note 1}	128	A
Body-drain diode reverse drain current	I_{DR}	16	A
Avalanche current	I_{AP} ^{Note 2}	16	A
Avalanche energy	E_{AR} ^{Note 2}	25.6	mJ
Channel dissipation	P_{ch} ^{Note 3}	2.0	W
Channel to ambient thermal impedance	θ_{ch-a} ^{Note 3}	62.5	$^\circ\text{C}/\text{W}$
Channel temperature	T_{ch}	150	$^\circ\text{C}$
Storage temperature	T_{stg}	-55 to +150	$^\circ\text{C}$

Notes: 1. $PW \leq 10 \mu\text{s}$, duty cycle $\leq 1\%$

2. Value at $T_{ch} = 25^\circ\text{C}$, $R_g \geq 50 \Omega$

3. When using the glass epoxy board (FR4 40 x 40 x 1.6 mm), $PW \leq 10\text{s}$

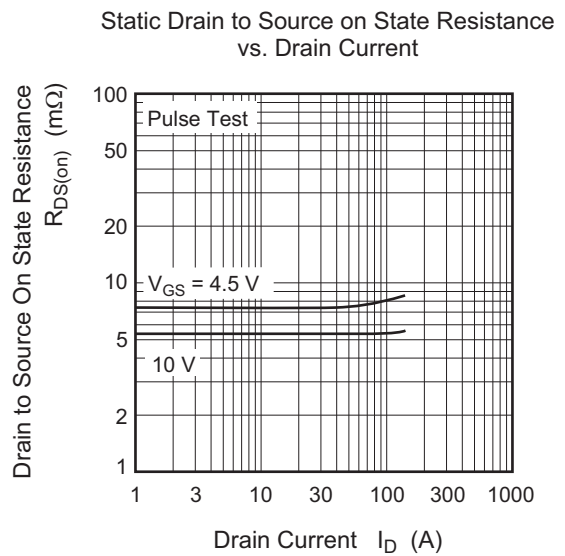
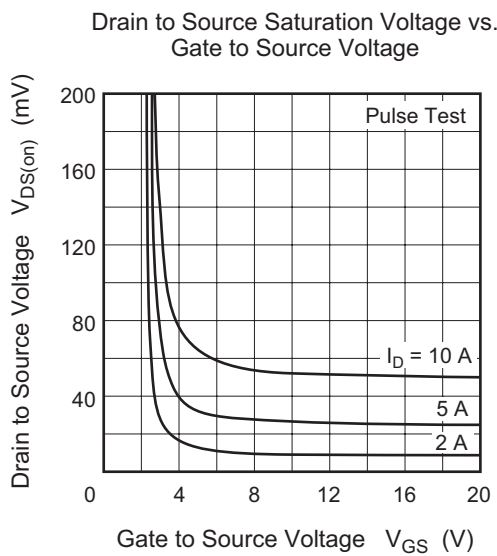
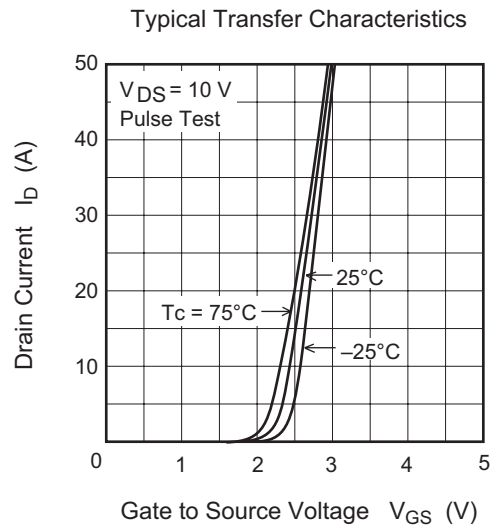
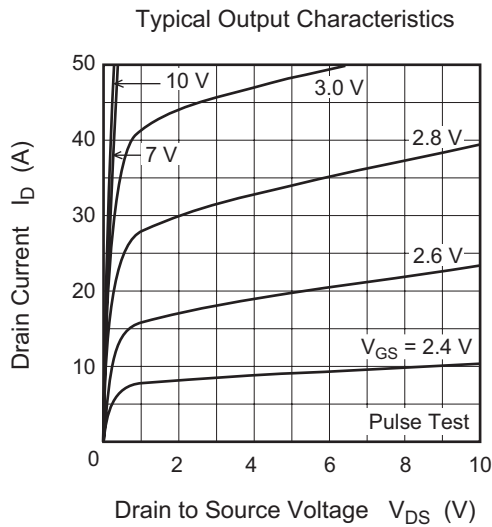
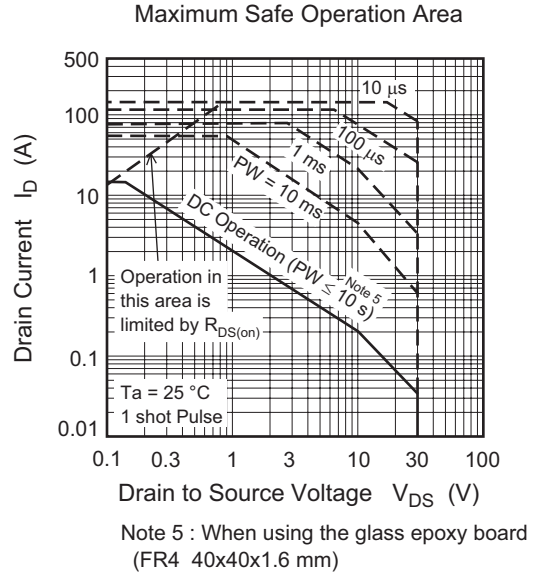
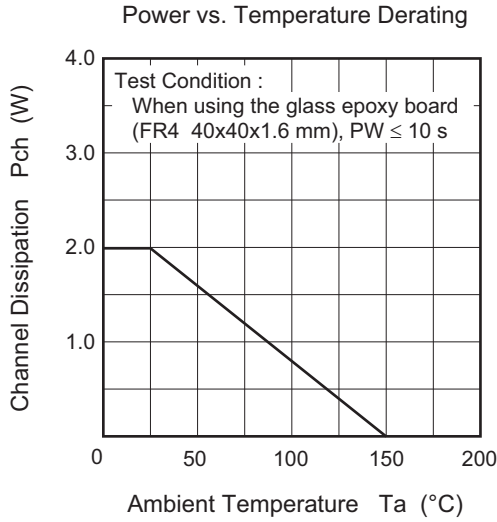
Electrical Characteristics

(Ta = 25°C)

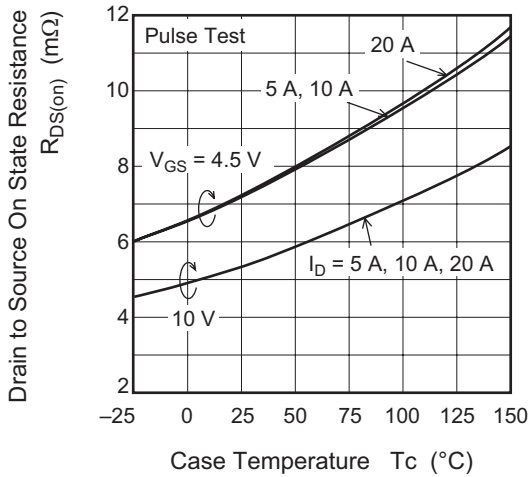
Item	Symbol	Min	Typ	Max	Unit	Test Conditions
Drain to source breakdown voltage	$V_{(BR)DSS}$	30	—	—	V	$I_D = 10 \text{ mA}$, $V_{GS} = 0$
Gate to source leak current	I_{GSS}	—	—	± 0.1	μA	$V_{GS} = +16/-12 \text{ V}$, $V_{DS} = 0$
Zero gate voltage drain current	I_{DSS}	—	—	1	μA	$V_{DS} = 30 \text{ V}$, $V_{GS} = 0$
Gate to source cutoff voltage	$V_{GS(off)}$	1.2	—	2.5	V	$V_{DS} = 10 \text{ V}$, $I_D = 1 \text{ mA}$
Static drain to source on state resistance	$R_{DS(on)}$	—	5.3	6.4	$\text{m}\Omega$	$I_D = 8 \text{ A}$, $V_{GS} = 10 \text{ V}$ ^{Note4}
	$R_{DS(on)}$	—	7.2	9.4	$\text{m}\Omega$	$I_D = 8 \text{ A}$, $V_{GS} = 4.5 \text{ V}$ ^{Note4}
Forward transfer admittance	$ y_{fs} $	—	40	—	S	$I_D = 8 \text{ A}$, $V_{DS} = 10 \text{ V}$ ^{Note4}
Input capacitance	C_{iss}	—	2080	—	pF	$V_{DS} = 10 \text{ V}$
Output capacitance	C_{oss}	—	650	—	pF	$V_{GS} = 0$
Reverse transfer capacitance	C_{rss}	—	100	—	pF	$f = 1 \text{ MHz}$
Gate Resistance	R_g	—	1.4	—	Ω	
Total gate charge	Q_g	—	13.8	—	nC	$V_{DD} = 10 \text{ V}$
Gate to source charge	Q_{gs}	—	5.3	—	nC	$V_{GS} = 4.5 \text{ V}$
Gate to drain charge	Q_{gd}	—	2.9	—	nC	$I_D = 16 \text{ A}$
Turn-on delay time	$t_{d(on)}$	—	6.5	—	ns	$V_{GS} = 10 \text{ V}$, $I_D = 8 \text{ A}$
Rise time	t_r	—	5.0	—	ns	$V_{DD} \cong 10 \text{ V}$
Turn-off delay time	$t_{d(off)}$	—	45	—	ns	$R_L = 1.25 \Omega$
Fall time	t_f	—	4.0	—	ns	$R_g = 4.7 \Omega$
Body-drain diode forward voltage	V_{DF}	—	0.81	1.06	V	$I_F = 16 \text{ A}$, $V_{GS} = 0$ ^{Note4}
Body-drain diode reverse recovery time	t_{rr}	—	30	—	ns	$I_F = 16 \text{ A}$, $V_{GS} = 0$ $di_F/dt = 100 \text{ A}/\mu\text{s}$

Notes: 4. Pulse test

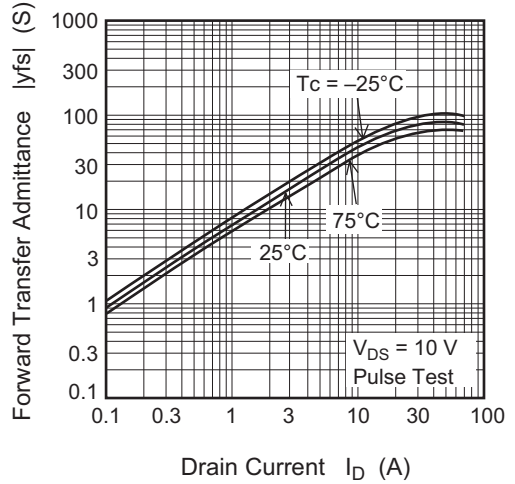
Main Characteristics



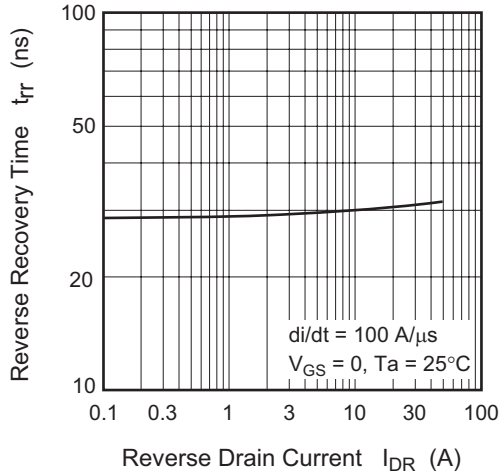
Static Drain to Source on State Resistance vs. Temperature



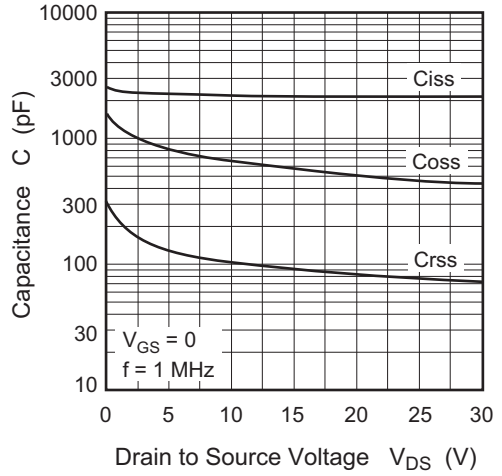
Forward Transfer Admittance vs. Drain Current



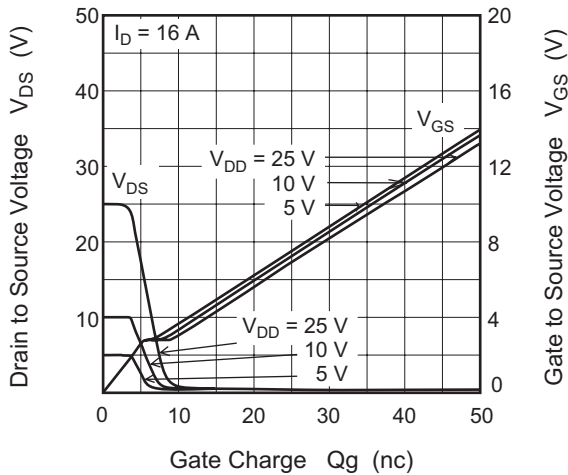
Body Drain Diode Reverse Recovery Time



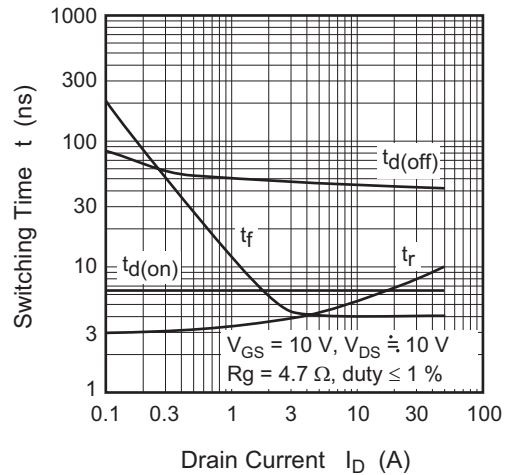
Typical Capacitance vs. Drain to Source Voltage

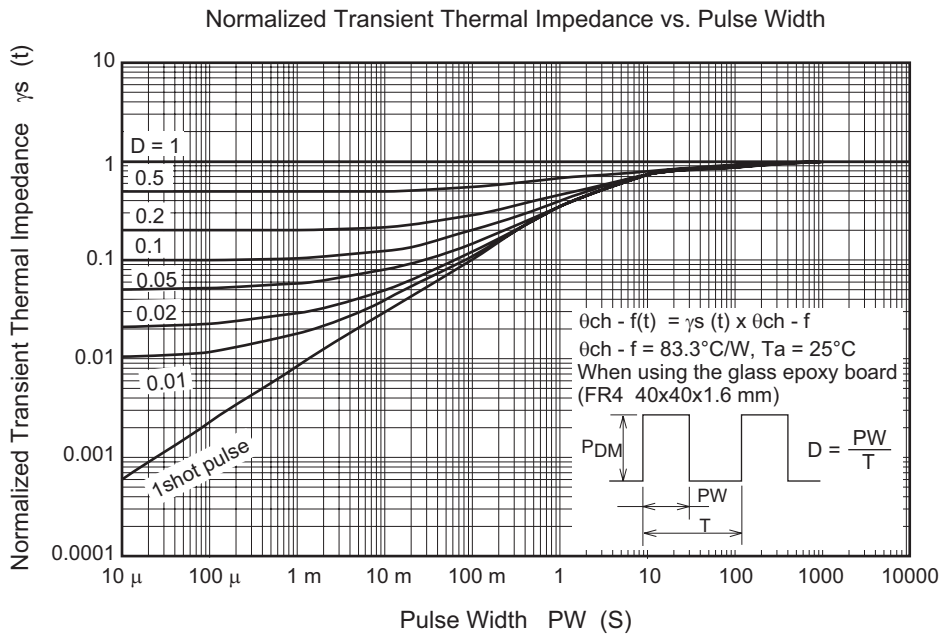
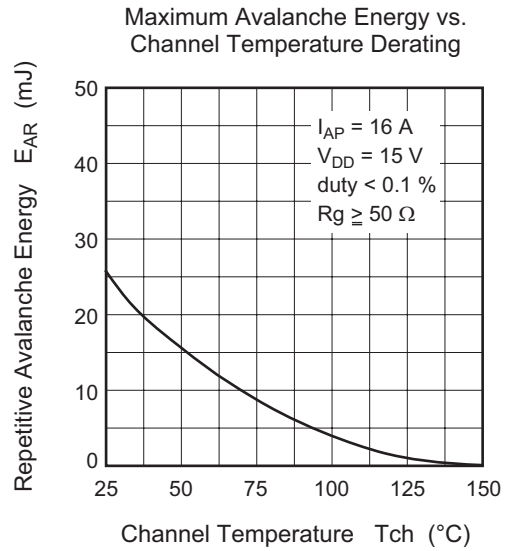
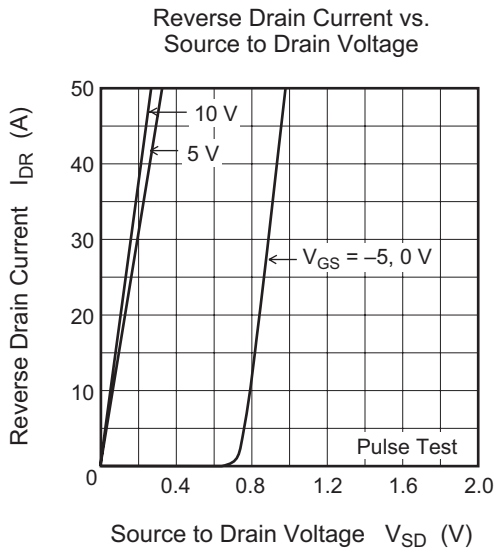


Dynamic Input Characteristics

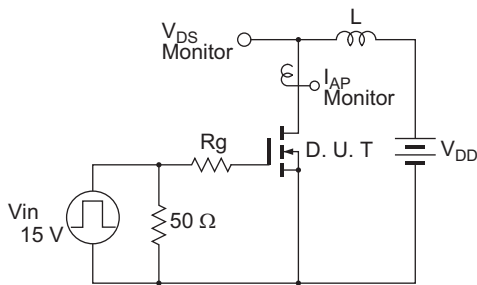


Switching Characteristics

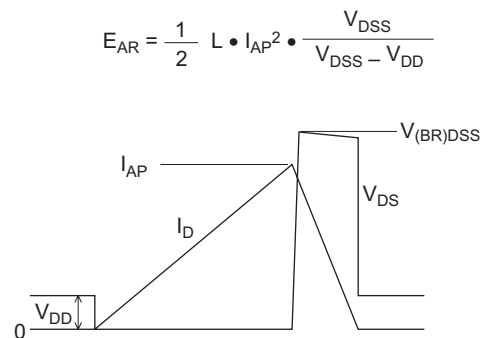


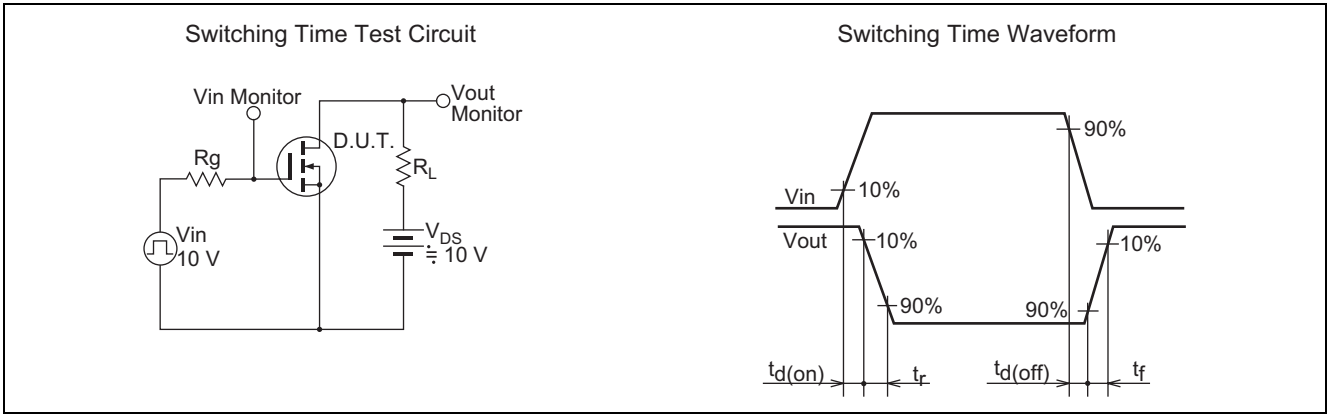


Avalanche Test Circuit

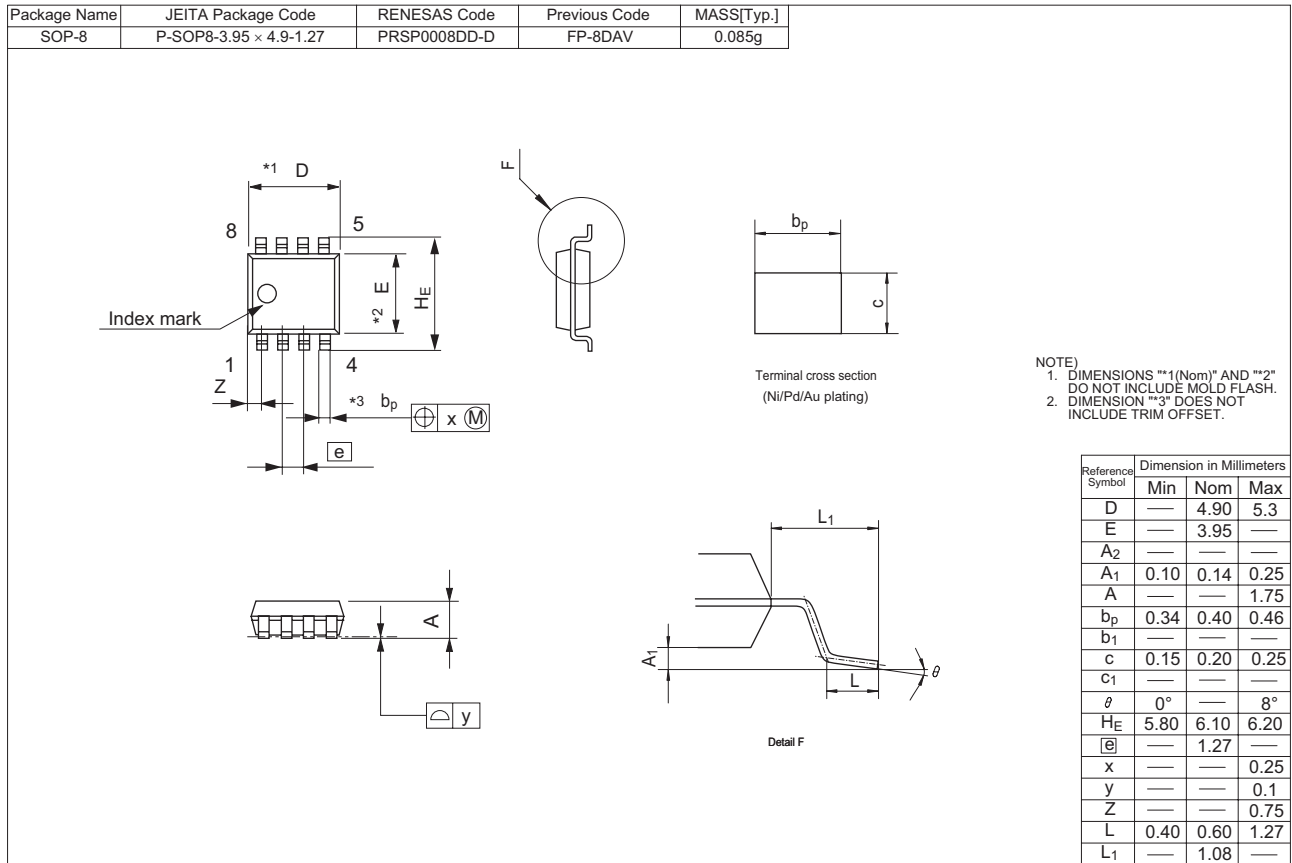


Avalanche Waveform





Package Dimensions



Ordering Information

Part Name	Quantity	Shipping Container
RJK0316DSP-00-J0	2500 pcs	Taping

Note: For some grades, production may be terminated. Please contact the Renesas sales office to check the state of production before ordering the product.

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